High Intensity SMD LED



This device has been designed to meet the increasing demand for white SMD LED.

The package of the VLMW33. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled with a mixture of epoxy and TAG phosphor.

The TAG phosphor converts the blue emission partially to yellow, which mixes with the remaining blue to give white.

FEATURES

- High efficient InGaN technology
- Chromaticity Coordinate categorized acc. to CIE1931 per packing unit
- Typical color temperature 5500 K
- ESD-withstand voltage up to 1 kV acc. to JESD22-A114-B
- · EIA and ICE standard package
- Compatible with IR-reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020C
- Available in 8 mm tape reel
- Lead (Pb)-free device
- Preconditioning: according to Jedec Level 2a
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- Automotive: Backlighting in dashboards and switches
- Telecommunication: Indicator and backlighting in telephone and fax
- · Backlighting for audio and video equipment
- Backlighting in office equipment
- Indoor and outdoor message boards
- Flat backlight for LCDs, switches and symbols
- Illumination purposes, alternative to incandescent lamps
- General use

PARTS TABLE			
PART	COLOR, LUMINOUS INTENSITY	ANGLE OF HALF INTENSITY (± ϕ)	TECHNOLOGY
VLMW33S2V1-5K8L-08	White, $I_V = (224 \text{ to } 900) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33S2V1-5K8L-18	White, $I_V = (224 \text{ to } 900) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33T2U2-5K8L-08	White, $I_V = (355 \text{ to } 710) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33T2U2-5K8L-18	White, $I_V = (355 \text{ to } 710) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33U2AA-5K8L-08	White, $I_V = (560 \text{ to } 1400) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33U2AA-5K8L-18	White, $I_V = (560 \text{ to } 1400) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33T2AA-5K8L-08	White, $I_V = (355 \text{ to } 1400) \text{ mcd}$	60°	InGaN/TAG on SiC
VLMW33T2AA-5K8L-18	White, $I_V = (355 \text{ to } 1400) \text{ mcd}$	60°	InGaN/TAG on SiC











ABSOLUTE MAXIMUM RATINGS ¹⁾ , VLMW33				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage ²⁾		V _R	5	V
DC Forward current	$T_{amb} \le 50 \ ^{\circ}C$	١ _F	30	mA
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.1	А
Power dissipation		P _V	127	mW
Junction temperature		Тj	100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	400	K/W

Note:

¹⁾ $T_{amb} = 25 \degree C$, unless otherwise specified

²⁾ Driving the LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS1), VLMW33, WHITE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	I _F = 20 mA	VLMW33S2V1	Ι _V	224		900	mcd
		VLMW33T2U2	Ι _V	355		710	mcd
		VLMW33U2AA	I _V	560		1400	mcd
		VLMW33T2AA	I _V	355		1400	mcd
Chromaticity coordinate x acc. to CIE 1931	I _F = 20 mA	VLMW33.	х		0.33		
Chromaticity coordinate y acc. to CIE 1931	I _F = 20 mA	VLMW33.	у		0.33		
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F		3.7	4.2	V
Reverse voltage	I _R = 10 μA		V _R	5			V
Temperature coefficient of V_F	I _F = 20 mA		TC _{VF}		- 4		mV/K
Temperature coefficient of I_V	I _F = 20 mA		TCIV		- 0.5		%/K

Note:

¹⁾ $T_{amb} = 25$ °C, unless otherwise specified

LUMINOUS INTENSITY CLASSIFICATION					
GROUP	LIGHT INTENSITY [MCD]				
STANDARD	OPTIONAL	MIN	MAX		
S	1	180	224		
3	2	224	280		
т	1	280	355		
I	2	355	450		
11	1	450	560		
0	2	560	710		
V	1	710	900		
v	2	900	1120		
AA	1	1120	1400		

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above Type Numbers represent the order groups which include only a few brightness groups.

Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

CROSSING TABLE				
VISHAY	OSRAM			
VLMW33S2V1	LWT67C-S2V1			
VLMW33T2U2	LWT67C-T2U2			



CHROMATICITY COORDINATED GROUPS FOR WHITE SMD LED						
	X	Y			X	Y
	0.291	0.268			0.330	0.330
	0.285	0.279		0.330	0.347	
5L	0.307	0.312		7L	0.347	0.371
	0.310	0.297			0.345	0.352
	0.296	0.259		7К	0.330	0.310
5K	0.291	0.268			0.330	0.330
JK	0.310	0.297			0.338	0.342
	0.313	0.284			0.352	0.344
	0.310	0.297		8L	0.345	0.352
CI.	0.307	0.312			0.347	0.371
6L	0.330	0.347			0.367	0.401
	0.330	0.330		0.364	0.380	
	0.313	0.284			0.352	0.344
6K	0.310	0.297	8K	ol/	0.338	0.342
ON	0.330	0.330		0.364	0.380	
	0.330	0.310	1		0.360	0.357

Note:

Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of ± 0.01

TYPICAL CHARACTERISTICS

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

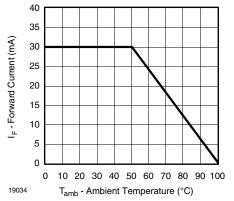


Figure 1. Forward Current vs. Ambient Temperature

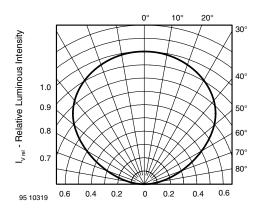


Figure 2. Rel. Luminous Intensity vs. Angular Displacement



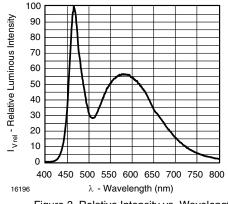


Figure 3. Relative Intensity vs. Wavelength

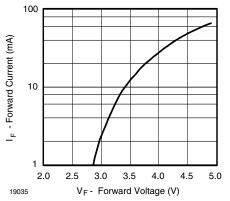


Figure 4. Forward Current vs. Forward Voltage

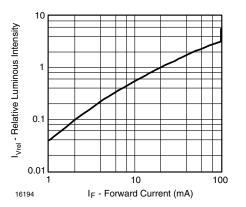


Figure 5. Relative Luminous Intensity vs. Forward Current

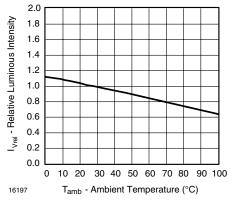


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

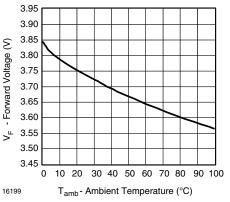


Figure 7. Forward Voltage vs. Ambient Temperature

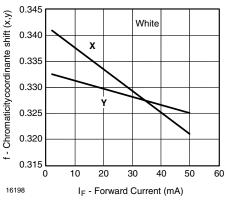
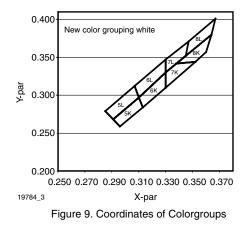


Figure 8. Chromaticity Coordinate Shift vs. Forward Current

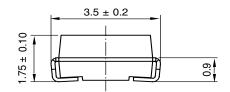


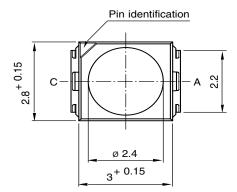
VLMW33.

Vishay Semiconductors



PACKAGE DIMENSIONS IN MM

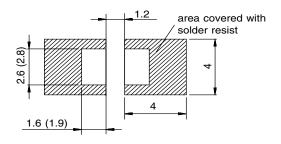




Drawing-No.: 6.541-5025.01-4 Issue: 8; 22.11.05

technical drawings according to DIN specifications

Mounting Pad Layout

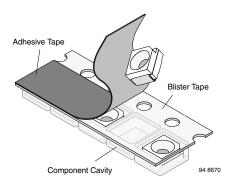




METHOD OF TAPING/POLARITY AND TAPE AND REEL

SMD LED (VLM.3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

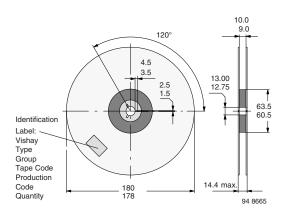


Figure 11. Reel dimensions - GS08

TAPING OF VLM.3...

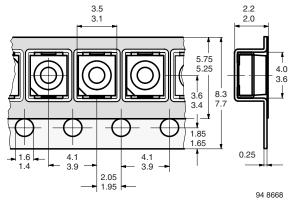


Figure 10. Tape dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERED

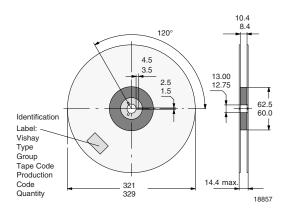
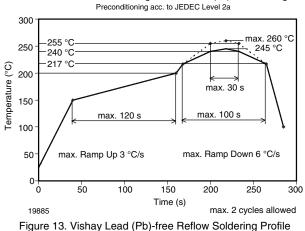


Figure 12. Reel dimensions - GS18





SOLDERING PROFILE



IR Reflow Soldering Profile for lead (Pb)-free soldering

Figure 13. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

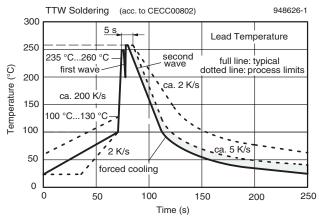
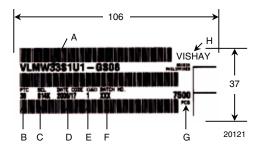


Figure 14. Double wave soldering of opto devices (all packages)

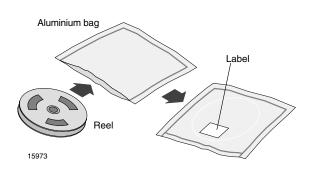
BARCODE-PRODUCT-LABEL EXAMPLE:



- A) Type of component
- B) Manufacturing Plant
- C) SEL Selection Code (Bin):
 - e.g.: S1 = Code for Luminous Intensity Group 4K = Code for Color Group
- D) Date Code year/week
- E) Day Code (e.g. 1: Monday)
- F) Batch No.
- G) Total quantity
- H) Company Code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity \leq 60 % RH max.

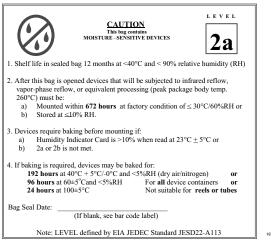
After more than 672 hours under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 hours at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/nitrogen) or

96 hours at 60 $^{\circ}\text{C}$ + 5 $^{\circ}\text{C}$ and < 5 % RH for all device containers or

24 hours at 100 °C + 5 °C not suitable for reel or tubes. An EIA JEDEC Standard JESD22-A112 Level 2a label is included on all dry bags.



Example of JESD22-A112 Level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the Antistatic Shielding Bag. Electro-Static Sensitive Devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR-CODE LABELS

The Vishay Semiconductors standard bar-code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.